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Quad Channel (Half X4 Lane) PCle Redriver/Equalizer

Check for Samples: SN65LVPE504

FEATURES

- 4 Identical Channel PCIe Equalizer/Redriver
- Support for Both PCle Gen I (2.5Gbps) and Gen II (5.0 Gbps) Speed
- Selectable Equalization, De-emphasis, and Output Swing
- Per Channel Receive Detect (Lane Detection)
- Selectable Receiver Electrical Idle Threshold Control
- Low Operating Power Modes
 - Supports Three Low-Power Modes to Enable up to 80% Lower Operating Power
- Excellent Jitter and Loss Compensation Capability to 50" of 4-mil SL on FR4
- Small Foot Print 42 Pin 9 x 3.5 TQFN Package
- High Protection Against ESD Transient

HBM: 6,000 VCDM: 1,000 V

MM: 200 V

DESCRIPTION

The SN65LVPE504 is a quad channel, half four lane PCIe redriver and signal conditioner supporting data rates of up to 5.0Gbps. The device complies with PCIe spec revision 2.1, supporting electrical idle and power management modes.

Programmable EQ, De-Emphasis and Amplitude Swing

The SN65LVPE504 is designed to minimize the signal degradation effects such as crosstalk and inter-symbol interference (ISI) that limits interconnect distance between two devices. The input stage of each channel offers selectable equalization settings that can be programmed to match loss in the channel. The differential outputs provide selectable de-emphasis to compensate for the anticipated distortion PCIe signal will experience. Both equalization and de-emphasis levels for all 4 channels are controlled by the setting of signal control pins EQ, DE and OS.

See Table 1 for EQ, DE and OS setting details.

APPLICATIONS

 PC MB, Docking Station, Server, Communication Platform, Backplane and Cabled Application

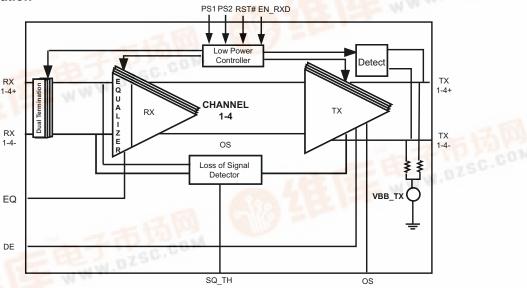


Figure 1. Data Flow Block Diagram

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DEVICE OPERATION

Device PowerOn

Device in<u>itiates</u> internal power-on reset after Vcc has stabilized. External reset can also be applied at anytime by toggling RST pin. External reset is recommended after every device power-up. After 50µs (MAX) from the application of RST, device samples the state of EN_RXD, if it is set H device will enter Rx.Detect state where each of the four channels will perform Rx.Detect function (as described in PCle spec). If EN_RXD is set L, automatic RX detect function is disabled and all channels are enabled with their termination set to Z_{RX_DC}.

Receiver Detection

While EN_RXD pin is H and device is not in reset state (\overline{RST} is H), LVPE504 performs RX.Detect on all its 4 channels indefinitely until remote termination is detected on at least one channel. When termination is detected on \geq 1 CH, RX.Detect cycle is limited to 5 more tries on the other channels. At the end of 5th try those channels which failed to detect remote termination will be turned off to save power and their Rx termination is set to $Z_{RX-HIGH}$. In the event device detects only three channels, all four channels are enabled.

Automatic Rx detection feature on all four channels can be forced off by driving EN_RXD low. In this state all four channels input termination are set to $Z_{RX\ DC}$.

Standby Mode

This is low power state triggered by $\overline{RST} = L$. In standby mode receiver termination resistor for each of the four channels is switched to $Z_{RX-HIGH}$ of >50 k Ω and transmitters are pulled to Hi-Z state. Device power is reduced to <10mW (TYP). To get device out of standby mode \overline{RST} is toggled L-H.

Electrical Idle Support

A link is in an electrical idle state when the TX \pm voltage is held at a steady constant value like the common mode voltage. LVPE504 detects an electrical idle state when RX \pm input voltage of the associated channel falls below V_{EID_TH} min and stays in this state for at least 20ns. After detection of an electrical idle state in a given channel the device asserts electrical idle state in its corresponding TX. When RX \pm voltage exceeds V_{EID_TH} max, normal operation is restored and output start passing input signal. Electrical idle exit and entry time is specified at < 8 ns (MAX).

Electrical idle support is independent for each channel, however to lower active power it is possible to slave electrical idle function from channel 1 to CH2-CH4. This mode is selected by driving PS2 to H.

Power Save Features

Device supports three power save modes as below:

1. Standby Mode

This mode can be enabled from any state (Rx detect or active) by driving \overline{RST} L. In this state all 4 channels have their termination set to $Z_{RX-HIGH}$ and outputs are at Hi-Z. Device power is 10mW (MAX).

Auto Low Power Mode

This mode is enabled when PS1 pin is tied H and device has been in active mode, i.e., past Rx detect state for >250ms (TYP). In this mode anytime Vin_{diff_p-p} falls below selected V_{EID_TH} for a *given channel* and stays below V_{EID_TH} for >1µs, the associated CH enters auto low power (ALP) mode where power/CH is reduced by >80% of normal operating power/CH. A CH will exit ALP mode whenever Vin_{diff_p-p} exceeds max V_{EID_TH} for that channel. Exit latency from ALP state is 30ns max. To use this mode link latency will need to account for the ALP exit time for N_FTS. ALP mode is handled by each channel independently based on its input differential signal level, unless slave mode is activated (PS2=H) when CH1 controls SQ detect of other channels based on its signal level.

3. Slave Power Mode

This mode is activated by driving PS2 high. Under normal operation squelch detection is handled by each channel independently. In slave mode SQ detection for CH2, CH3 and CH4 are turned off and squelch function is slaved to that of CH1. By turning off squelch detection circuitry for three of the four channels device saves power. To use this feature user must ensure all channels operate simultaneously

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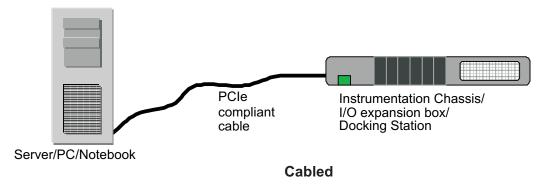
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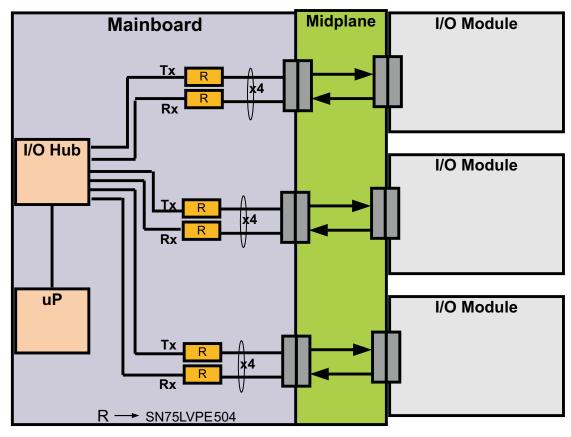
Squelch Control

Controls electrical idle detect threshold level. Three levels are supported as shown in Table 1.

Beacon Support

With its broadband design, the SN65LVPE504 supports low frequency Beacon signal (as defined by PCIe 2.1 spec) used to indicate wake-up event to the system by a downstream device when in L2 power state. All requirements for a beacon signal as specified in PCI Express specification 2.1 must be met for device to pass beacon signals.





Backplane

Figure 2. LVPE504 Typical Applications



DEVICE INFORMATION

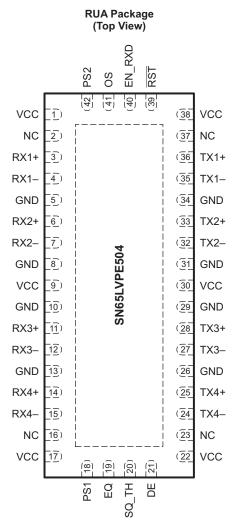


Figure 3. Flow-Through Pin-Out

PIN FUNCTIONS

PIN	I	VO TYPE	DESCRIPTION							
NO.	NAME	I/O TYPE	DESCRIPTION							
HIGH SPEED D	HIGH SPEED DIFFERENTIAL I/O PINS									
3	RX1+									
4	RX1-									
6	RX2+									
7	RX2-	LOM	Non-inverting and inverting CML differential input for CH 1 and CH 4. These pins are tied to an internal voltage							
11	RX3+	i, CML bias by dual termination resistor circuit	bias by dual termination resistor circuit							
12	RX3-									
14	RX4+									
15	RX4-									
36	TX1+									
35	TX1-	O CMI	Non-inverting and inverting CML differential output for CH 1 and CH 4. These pins are internally tied to voltage							
33	TX2+	O, CML	bias by termination resistors							
32	TX2-									

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PIN FUNCTIONS (continued)

NO. NAME		UO TVDE	DEGODITATION			
		I/O TYPE	DESCRIPTION			
HIGH SPEED DI	FFERENTIA	L I/O PINS (co	ontinued)			
28	TX3+					
27	TX3-	0.004	Non-inverting and inverting CML differential output for CH 1 and CH 4. These pins are internally tied to voltage			
25	TX4+	O, CML	bias by termination resistors			
24	TX4-					
DEVICE CONTR	OL PIN					
40	EN_RXD	I, LVCMOS	Sets device operation modes per Table 1. Internally pulled to VCC			
42	PS2	I, LVCMOS	Tying pin to VCC slaves CH2-4 electrical idle and Rx.Detect function to CH1. Internally pulled to GND			
18	PS1	I, LVCMOS	Select auto-low power save mode per Table 1. Internally pulled to GND			
20	SQ_TH ⁽¹⁾	I, LVCMOS	Squelch threshold level select pin for electrical idle detect per Table 1 Internally pulled to VCC/2			
39	RST	I, LVCMOS	Reset device, input active Low. Internally pulled to VCC			
SIGNAL CONDI	TIONING PIN	IS ⁽¹⁾				
21	DE	I, LVCMOS	Selects de-emphasis settings for CH 1-CH 4 per Table 1. Internally pulled to Vcc/2			
19	EQ	I, LVCMOS	Selects equalization settings for CH 1-CH 4 per Table 1. Internally pulled to Vcc/2			
41	OS	I, LVCMOS	Selects output amplitude for CH 1-CH 4 per Table 1. Internally pulled to Vcc/2			
POWER PINS						
1,9,17,22,30,38 VCC Power			Positive supply should be 3.3V ± 10%			
5,8,10,13, 26,29,31,34û GND Power			Supply ground			

⁽¹⁾ Internally biased to Vcc/2 with >200k Ω pull-up/pull-down. When 3-state pins are left as NC, board leakage at the pin pad must be < 1 μ A otherwise drive to Vcc/2 to assert mid-level state.

Table 1. Control Pin Settings

OU	TPUT SWING (CH1-CH4) at 5Gb	ps	SQUELCH T	HRESHOLD (CH1-CH4)			
os TR/		TRANSITION BIT AMPLITUDE (TYP mVpp)		SQ_TH	MIN DIFFERENTIAL INPUT (CH1-CH4)			
0 80			0	0	47 mVpp			
NC (de	NC (default) 929			NC (default)	61 mVpp			
1		104	47	1	83 mVpp			
OUTPU	IT DE-EMPHAS	SIS (CH1-CH4) at	5Gbps	INPUT EQU	ALIZATION (CH1-CH4)			
DE	DE OS = NC OS = 0			EQ	Equalization dB (at 5Gbps)			
NC (default)	-3.4dB	-2.1dB	-4.6dB	0	0			
0	-6.2dB	-4.9dB	-7.2dB	NC	7 (default)			
1	1 –10.3dB		-11dB	1	15			
EN_RXD		DEVICE FUNCTION						
		0	Set input termination to Rx_DC					
		1	Perform Rx detect after power up					
	Ī	RST	DE	DEVICE FUNCTION				
		0	Device in standby state, inputs set to Hi-Z					
		1	Device in active	Device in active mode				
	ı	PS1	DEVICE FUNCTION					
		0	Auto-low power mode disabled (<i>default</i>)					
1			Auto-low power mode enabled					
PS2			DEVICE FUNCTION					
0			Electrical Idle and Rx Detect independent for CH1-CH4 (<i>default</i>)					
		1	CH2-CH4 Elec	trical Idle and Rx Detect slaved	to CH1			

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ORDERING INFORMATION(1)

PART NUMBER	PART MARKING	PACKAGE
SN65LVPE504RUAR	LVPE504	42-pin RUA Reel (large)

⁽¹⁾ For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)(1)

		VALUE	UNIT
Supply voltage range (2)	V _{CC}	-0.5 to 4	V
Valtaga nanga	Differential I/O	-0.5 to 4	V V V V V V
Voltage range	Control I/O	-0.5 to VCC + 0.5	V
	Human body model ⁽³⁾	±6000	V
Electrostatic discharge	Charged-device model (4)	±1000	V
	Machine model ⁽⁵⁾	±200	V
Continuous power dissipation	on .	See Thermal Table	

⁽¹⁾ Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- 2) All voltage values, except differential voltages, are with respect to network ground terminal.
- (3) Tested in accordance with JEDEC Standard 22, Test Method A114-B
- (4) Tested in accordance with JEDEC Standard 22, Test Method C101-A
- (5) Tested in accordance with JEDEC Standard 22, Test Method A115-A

THERMAL INFORMATION

	THERMAL METRIC	SN65LVPE504	LINUTO
	THERMAL METRIC	TQFN (42 PINS)	UNITS
θ_{JA}	Junction-to-ambient thermal resistance	30	
θ_{JCtop}	Junction-to-case (top) thermal resistance	12	
θ_{JB}	Junction-to-board thermal resistance	10	°C/W
ΨЈТ	Junction-to-top characterization parameter	0.5	*C/VV
ΨЈВ	Junction-to-board characterization parameter	9	
θ_{JCbot}	Junction-to-case (bottom) thermal resistance	4.7	

RECOMMENDED OPERATING CONDITIONS

		MIN	TYP	MAX	UNITS
V _{CC}	Supply voltage	3	3.3	3.6	V
C _{COUPLING}	AC Coupling capacitor	75		200	nF
	Operating free-air temperature	-40		85	°C

Product Folder Link(s): SN65LVPE504

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ELECTRICAL CHARACTERISTICS

under recommended operating conditions

	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS	
DEVICE PARAM	IETERS						
I _{CC}		RST, DEx, EQx, OS = NC, EN_RXD = NC, K28.5 pattern at 5 Gbps, VID = 1000mVp-p		174	190		
ICC _{Slave}		PS2 = Vcc; RST, DEx, EQx, OS = NC, EN_RXD = NC, K28.5 pattern at 5 Gbps, V _{ID} = 1000mV _{p-p}		161	175		
ICC _{ALP}	Supply current	When auto-low power conditions are met, $PS1 = V_{CC}$		27	32	mA	
ICC _{ALP _Slave}		PS1, PS2 = VCC and link in EID state		14	18		
ICC _{NO_CONNECT}		EN_RXD = 1 No termination detected on any CH		2.5			
ICC _{stdby}		RST = GND			0.1		
	Maximum data rate				5	Gbps	
AutoLP _{ENTRY}	Auto low power entry time	Electrical idle at input, Refer to Figure 7		1		μs	
AutoLP _{EXIT}	Auto low power exit time	After first signal activity, Refer to Figure 7			30	ns	
t _{ENB}	Device enable time	<u>RST</u> 0 → 1		5	50	μs	
t _{DIS}	Device disable time	$\overline{RST}\ 1 \to 0$		0.1	2	μs	
T _{RX.Detect}	Rx.Detect start event	EN_RXD = 1, Time to start Rx Detect after power up		6		μs	
CONTROL LOG	IC						
V _{IH}	High level Input Voltage		1.4		Vcc	V	
V _{IL}	Low Level Input Voltage		-0.3		0.5	V	
V _{HYS}	Input Hysteresis			150		mV	
	High Loyal Input Current	OS, EQ, DE, SQ_TH, PS1, PS2 = V _{CC}			30		
lін	High Level Input Current	Input Current $EN_RXD, \overline{RST} = V_{CC}$			1	μA	
1	Low Lovel Input Current	PS1, PS2 = GND	-1				
I _{IL}	Low Level Input Current	OS, EQ, DE, SQ_TH, EN_RXD, \overline{RST} = GND				μA	
RECEIVER AC/	OC						
Vin _{diff_p-p}	RX1-RX4 Input voltage swing	AC coupled differential signal (5Gbps)	100		1200	mVp-p	
T _{RX_TJ}	Max Rx total timing error	At device pin (5Gbps)			0.4	UI	
T _{RX_DJ}	Max Rx deterministic timing error	At device pin (5Gbps)			0.3	UI	
V _{CM_RX}	RX1-RX4 Common mode voltage		0		3.6	V	
Vin _{COM_P}	RX1-RX4 AC peak common mode voltage				150	mVP	
Z _{RX_DC}	DC single ended impedance		40	55	60	Ω	
Z _{RX_Diff}	DC Differential input impedance		80	98	120	Ω	
Z _{RX_High}	DC Input high impedance	Device in standby mode. Rx termination not powered measured with respect to GND over 200 mV max	50	75		kΩ	
		Measured at receiver pin: SQ_TH = NC		61			
V_{EID_TH}	Electrical idle detect threshold	SQ_TH = 1	58	83	107	mVpp	
		SQ_TH = 0		47			
DI	Differential return lass	50 MHz – 1.25 GHz	10	15		٩D	
RL _{RX-DIFF}	Differential return loss	1.25 GHz – 2.5 GHz	8	11		dB	
RL _{RX-CM}	Common mode return loss	50 MHz – 2.5 GHz	9	14		dB	



ELECTRICAL CHARACTERISTICS (continued)

	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNITS
TRANSMITTER	AC/DC					
		RL = $100\Omega \pm 1\%$, OS = NC, transition Bit	866	929	1031	
		RL = $100\Omega \pm 1\%$, OS = GND transition Bit		800		
		RL = $100\Omega \pm 1\%$ OS = VCC transition Bit		1047		
V_{TXDIFF_P-P}	Differential peak-to-peak output voltage	RL = $100\Omega \pm 1\%$, DE=NC, OS = $0,1,NC$ on-transition bit		620		mV
		RL = $100\Omega \pm 1\%$, DE=OS = 0,1,NC on-transition bit		456		
		RL = $100\Omega \pm 1\%$, DE=OS = 0,1,NC on-transition bit		288		
			-3.0	-3.4	-4.0	
	De-emphasis level	OS = NC (Figure 9) for OS = 1 and NC see	-5.5	-6.2	-6.5	dB
		Table 1)	-9.0	-10.3	-10.6	
T _{DE}	De-emphasis width	At 5 Gbps		0.9		UI
Z _{TX_diff}	DC Differential impedance	Defined during signaling	80	100	120	Ω
		f = 50 MHz – 1.25 GHz	10	20		dB
RL_{diff_TX}	Differential return loss	f = 1.25 GHz – 2.5 GHz	8	13	-	
RL _{CM TX}	Common mode return loss	f = 50 MHz – 2.5 GHz	6	12		dB
I _{TX_SC}	TX short circuit current	TX± shorted to GND		44	90	mA
V _{TX_CM_DC}	Transmitter DC common-mode voltage	Allowed DC CM voltage at TX pins		1.8	2.2	V
V _{TX_CM_AC2}	TX AC common mode voltage at Gen II speed	$Max(V_{d+} + V_{d-})/2 - Min(V_{d+} + V_{d-})/2$		30	100	mVpp
V _{TX_CM_AC1}	TX AC common mode voltage at Gen I speed	$RMS(V_{d+} + V_{d-})/2 - DC_{AVG}(V_{d+} + V_{d-})/2$		3	20	mV
V _{TX_CM_DeltaL0} -	Absolute Delta DC CM voltage during active and idle states	V _{TX_CM_DC [L0]} - VTX_CM_DC [L0 _s]	0		100	mV
V _{TX_CM-DC-Line} -	Absolute delta of DC CM voltage between D+ and D-	V _{TX_CM_DC-D+} [Lo] = V _{TX_CM_DC-D-} [Lo]	0		25	mV
V _{TX_idle_diff-AC-p}	Electrical idle differential peak output voltage	V _{TX-Idle-D+} - V _{TX-Idle-D-} , LP filtered to remove any DC component	0	1	20	mVpp
V _{TX_idle_diff-DC}	DC electrical idle differential output voltage	V _{TX_idle-D+} - V _{TX_idle-D} , LP filtered to remove any AC component		1.9		mV
V _{detect}	Voltage change to allow receiver detect	Positive voltage to sense receiver			600	mV
t _R ,t _F	Output rise/fall time	De-Emphasis = 0 dB, OS = NC (CH 0 and CH 1) 20%-80% of differential voltage at the output	30	55	70	ps
t _{RF_MM}	Output rise/fall time mismatch	De-Emphasis = 0dB, OS = NC (CH 0 and CH 1) 20%-80% of differential voltage at the output			20	ps
T _{diff_LH} , T _{diff_HL}	Differential propagation delay	De-Emphasis = 0dB (CH 0 and CH 1). Propagation delay between 50% level at input and output		280	350	ps
T _{INTRA_SKEW}	Output skew (same lane)	5 Gbps			15	ps
T _{INTER_SKEW}	Lane to lane skew	5 Gbps	-25		25	ps
idleEntry, tidleExit	Idle entry and exit times	See Figure 5			8	ns
$\Gamma_{tx_EID_min}$	Minimum time in EID		20			ns
	ON AT GEN II SPEED	-				
TX _{DJ} ⁽¹⁾		At point A1 in Figure 8, EQ/DE=NC, OS=HIGH		25	60	
-	Residual deterministic jitter	At point A2 in Figure 8, EQ/DE=NC, OS=LOW		26	60	ps p-p
	,	At point B in Figure 8, EQ/DE=NC, OS=HIGH		27	60	
		D24.3 pattern at point A1/A2/B in Figure 8			0.1	

⁽¹⁾ Refer to Figure 8 with ±K28.5 pattern, -3.5dB DE from source AWG

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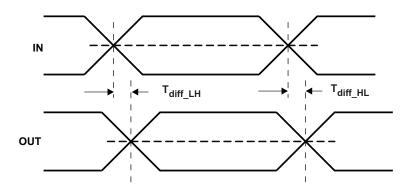


Figure 4. Propagation Delay

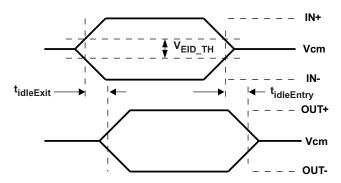


Figure 5. Idle Mode Exit and Entry Delay

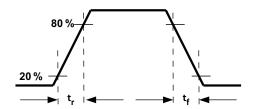


Figure 6. Output Rise and Fall Times

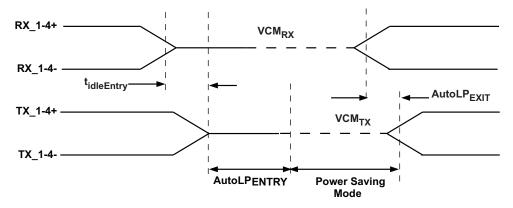


Figure 7. Auto Low Power Mode Timing (when enabled)



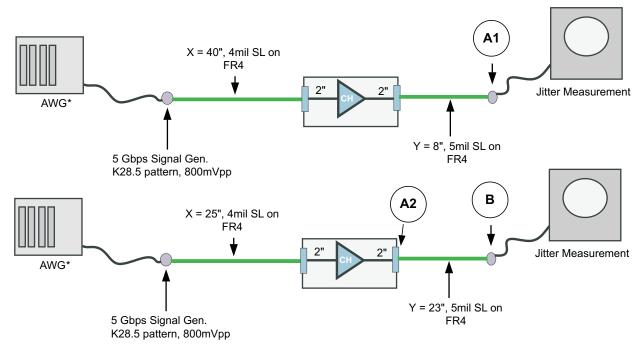


Figure 8. Jitter Measurement Setup

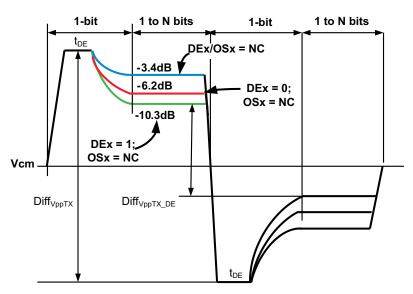


Figure 9. Output De-Emphasis Levels

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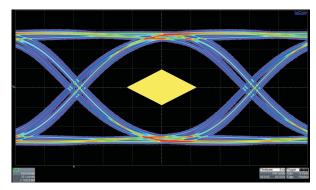
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TYPICAL CHARACTERISTICS

TYPICAL EYE DIAGRAM AND PERFORMANCE CURVES

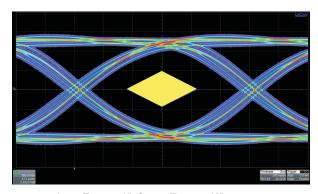
- Input Signal Characteristics VID = 1000mVpp, DE = -3.5 dB, Pattern = K28.5
- Device Operating Conditions: VCC = 3.3 V, Temp = 25°C
- All trace are 4 mils
- PCIe Gen I and Gen II compliance mask shown

AT GEN II SPEED



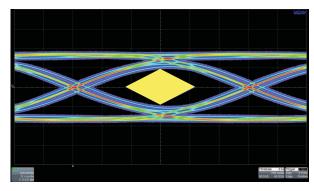
Input Trace = 4", Output Trace = 8" EQ = 0 dB, OS = 833 mVpp, DE = -1.9 dB

Figure 10.



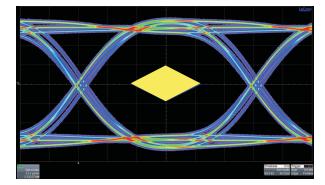
Input Trace = 4", Output Trace = 16" EQ = 0 dB, OS = 1166 mVpp, DE = -4.9 dB

Figure 11.



Input Trace = 4", Output Trace = 28" EQ = 0 dB, OS = 1166 mVpp, DE = -7.4 dB

Figure 12.

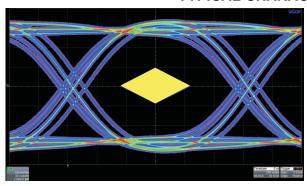


Input Trace = 16", Output Trace = 4" EQ = 0 dB, OS = 833 mVpp, DE = -1.9 dB

Figure 13.

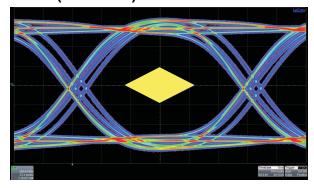


TYPICAL CHARACTERISTICS (continued)



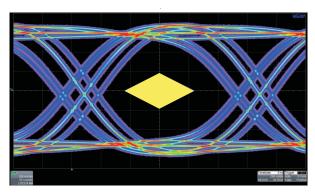
Input Trace = 28", Output Trace = 4" EQ = 7 dB, OS = 833 mVpp, DE = -1.9 dB

Figure 14.



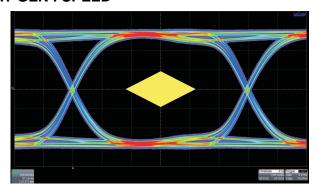
Input Trace = 36", Output Trace = 4" EQ = 7 dB, OS = 833 mVpp, DE = -1.9 dB

Figure 15.



Input Trace = 48", Output Trace = 4" EQ = 15 dB, OS = 833 mVpp, DE = -1.9 dB **Figure 16.**

AT GEN I SPEED



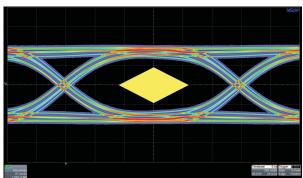
Input Trace = 4", Output Trace = 8" EQ = 7 dB, OS = 833 mVpp, DE = -1.9 dB **Figure 17.**

Input Trace = 4", Output Trace = 16" EQ = 7 dB, OS = 1166 mVpp, DE = -4.9 dB

Figure 18.

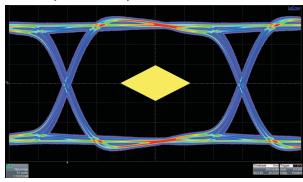
www.thcom/ICEL \/DEE0/"(# 应 商

TYPICAL CHARACTERISTICS (continued)



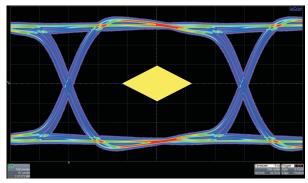
Input Trace = 4", Output Trace = 28" EQ = 7 dB, OS = 1166 mVpp, DE = -7.4 dB

Figure 19.



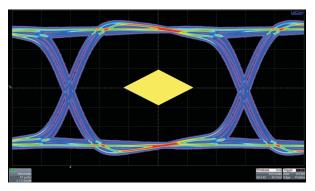
Input Trace = 16", Output Trace = 4" EQ = 7 dB, OS = 833 mVpp, DE = -1.9 dB

Figure 20.



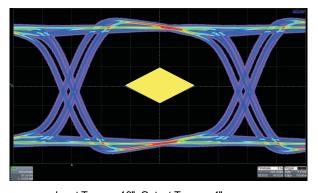
Input Trace = 28", Output Trace = 4" EQ = 15 dB, OS = 833 mVpp, DE = -1.9 dB

Figure 21.



Input Trace = 36", Output Trace = 4" EQ = 15 dB, OS = 833 mVpp, DE = -1.9 dB

Figure 22.



Input Trace = 48", Output Trace = 4" EQ = 15 dB, OS = 833 mVpp, DE = -1.9 dB **Figure 23.**



PACKA

PACKAGING INFORMATION

Orderable Device	Status ⁽¹⁾	Package Type	Package Drawing	Pins	Package Qty	Eco Plan ⁽²⁾	Lead/ Ball Finish	MSL Pe
SN65LVPE504RUAR	ACTIVE	WQFN	RUA	42	3000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-2-260

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

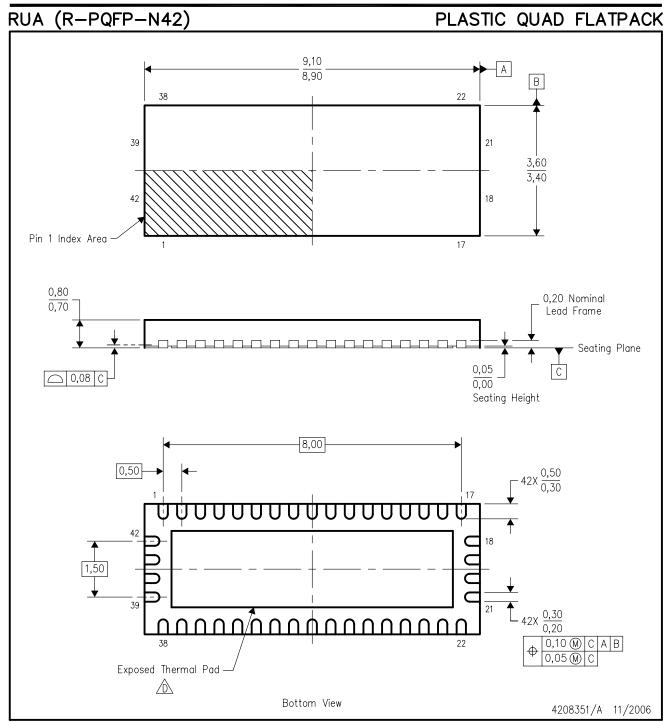
Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retard in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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NOTES: A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M-1994.

- B. This drawing is subject to change without notice.
- C. QFN (Quad Flatpack No-Lead) package configuration.
- The package thermal pad must be soldered to the board for thermal and mechanical performance. See the Product Data Sheet for details regarding the exposed thermal pad dimensions.



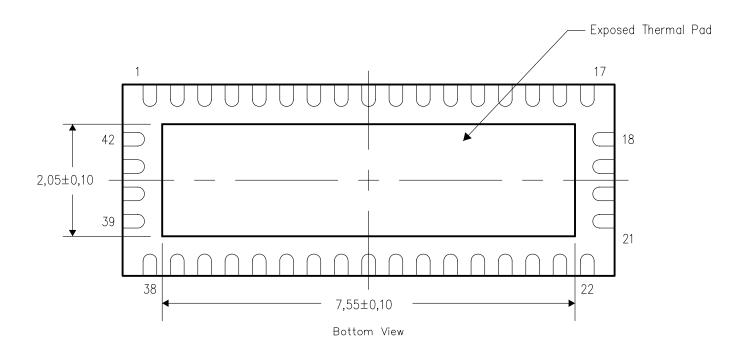


THERMAL INFORMATION

This package incorporates an exposed thermal pad that is designed to be attached directly to an external heatsink. The thermal pad must be soldered directly to the printed circuit board (PCB). After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For information on the Quad Flatpack No—Lead (QFN) package and its advantages, refer to Application Report, Quad Flatpack No—Lead Logic Packages, Texas Instruments Literature No. SCBA017. This document is available at www.ti.com.

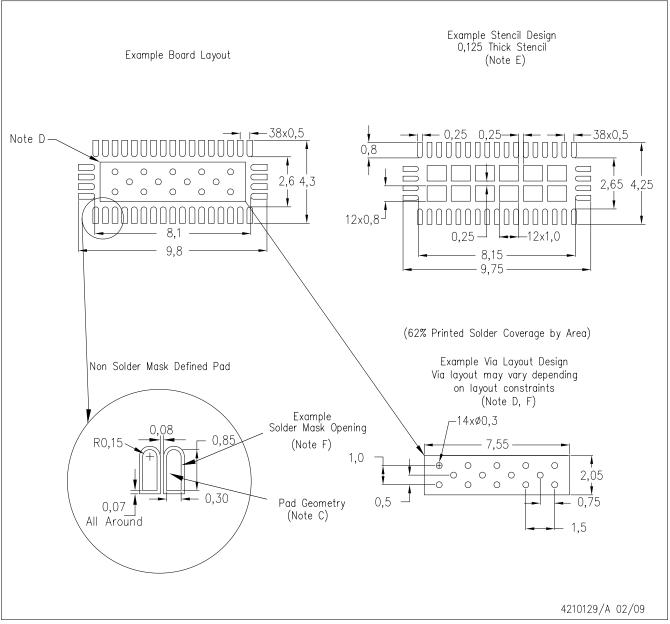
The exposed thermal pad dimensions for this package are shown in the following illustration.



NOTE: All linear dimensions are in millimeters

Exposed Thermal Pad Dimensions

RUA (R-PWQFN-N42)



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Application Note, Quad Flat—Pack Packages, Texas Instruments Literature No. SCBA017, SLUA271, and also the Product Data Sheets for specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com http://www.ti.com>.
- E. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC 7525 for stencil design considerations.
- F. Customers should contact their board fabrication site for recommended solder mask tolerances and via tenting recommendations for vias placed in the thermal pad.



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